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FDD8445

N-Channel PowerTrench[®] MOSFET 40V, 50A, 8.7m Ω

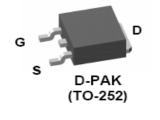
Features

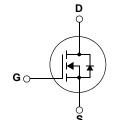
- $R_{DS(ON)} = 6.7 \text{ m}\Omega$ (Typ), $V_{GS} = 10V$, $I_D=50A$
- Q_{g(10)} = 45nC (Typ), V_{GS}=10V
- Low Miller Charge
- Low Qrr Body Diode
- UIS Capability (Single Pulse/ Repetitive Pulse)
- RoHS Compliant

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Applications

- Powertrain Management
- Electronic Transmission
- Distributed Power Architecture and VRMs
- Primary Switch for 12V Systems





April 2015

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Symbol	Parameter	Ratings	Units
V _{DSS}	Drain to Source Voltage	40	V
V _{GS}	Gate to Source Voltage	±20	V
	Drain Current Continuous (V _{GS} =10v) (Note 1)	70	Α
I _D	Continuous (V _{GS} =10v,with $R_{\theta JA} = 52^{\circ}C/W$)	15.2	A
	Pulsed	Figure 4	
E _{AS}	SinglePulseAvalancheEnergy (Note2)	144	mJ
D	Power Dissipation	79	W
P _D	Derate above 25°C	0.53	W/ºC
T _J , T _{STG}	Operating and Storage Temperature	-55 to +175	°C

Thermal Characteristics

$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	1.9	°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient TO-252, lin ² copper pad area	52	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD8445	FDD8445	TO-252AA	13"	16mm	2500 units

Electrical Characteristics $T_J = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Charac	steristics					

BV _{DSS}	Drain to Source Breakdown Voltage	$I_{D} = 250 \mu A, V_{C}$	_{GS} = 0V	40	-	-	V
1	Zero Gate Voltage Drain Current	$V_{DS} = 32V$		-	-	1	μA
DSS	Zero Gale voltage Drain Current	$V_{GS} = 0V$	T _J =150°C	-	-	250	
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA

On Characteristics

V _{GS(th)}	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	2	2.8	4	V
		$I_{D} = 50A, V_{GS} = 10V$	-	6.7	8.7	
R _{DS(ON)}	Drain to Source On Resistance	I _D = 50A, V _{GS} = 10V, T _J = 175°C	-	12.5	16.3	mΩ

Dynamic Characteristics

C _{ISS}	Input Capacitance			-	3040	4050	pF
C _{OSS}	Output Capacitance	$V_{DS} = 25V, V_{GS}$ = 1MHz	= 0V,	-	295	390	pF
C _{RSS}	Reverse Transfer Capacitance			-	178	270	pF
R _G	Gate Resistance	f = 1MHz		-	1.7	-	Ω
Q _{g(TOT)}	Total Gate Charge at 10V	$V_{GS} = 0$ to 10V		-	45	59	nC
Q _{g(5)}	Total Gate Charge at 5V	$V_{GS} = 0$ to 5V		-	17	22	nC
Q _{g(TH)}	Threshold Gate Charge	$V_{GS} = 0$ to 2V	V _{DD} =20V,	-	5.8	7.6	nC
Q _{gs}	Gate to Source Gate Charge		$I_D = 50A$	-	12.5	-	nC
Q _{gs2}	Gate Charge Threshold to Plateau			-	9.5	-	nC
Q _{gd}	Gate to Drain "Miller" Charge			-	10.5	-	nC

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Switchin	g Characteristics					
t _(on)	Turn-On Time		-	-	138	ns
t _{d(on)}	Turn-On Delay Time	V_{DD} = 20V, I _D = 50A V _{GS} = 10V, R _{GS} = 2Ω	-	10	-	ns
t _r	Turn-On Rise Time		-	82	-	ns
t _{d(off)}	Turn-Off Delay Time		-	26	-	ns
t _f	Turn-Off Fall Time		-	9.6	-	ns
t _{off}	Turn-Off Time		-	-	53	ns

I_F= 50A, dI_F/dt=100A/μs

I_F= 50A, dI_F/dt=100A/μs

t_{rr} Q_{rr}

Reverse Recovery Time

Reverse Recovery Charge

Notes: 1: Maximum package current capability is 50A. 2: Starting $T_J = 25^{\circ}C$, L=0.18mH, I_{AS}=40A.

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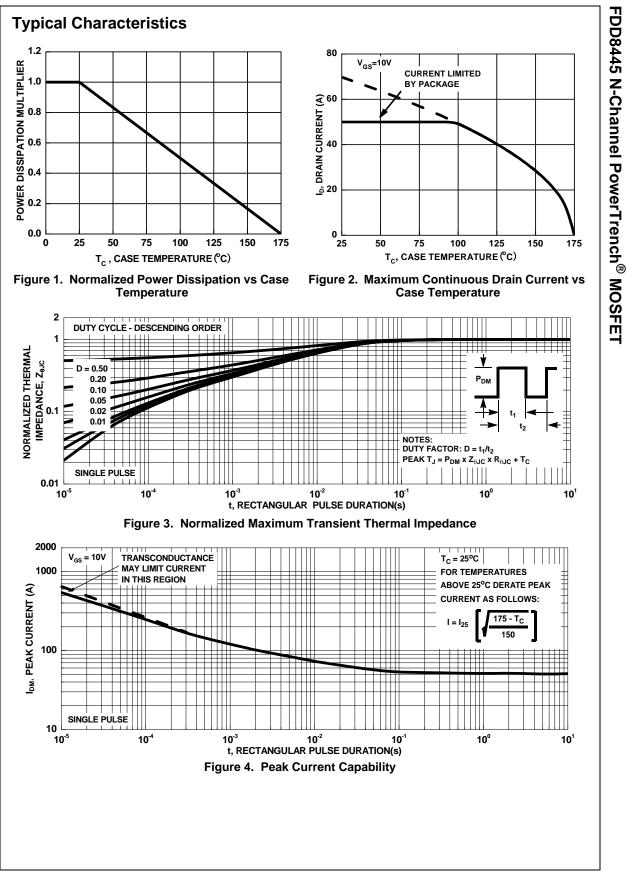
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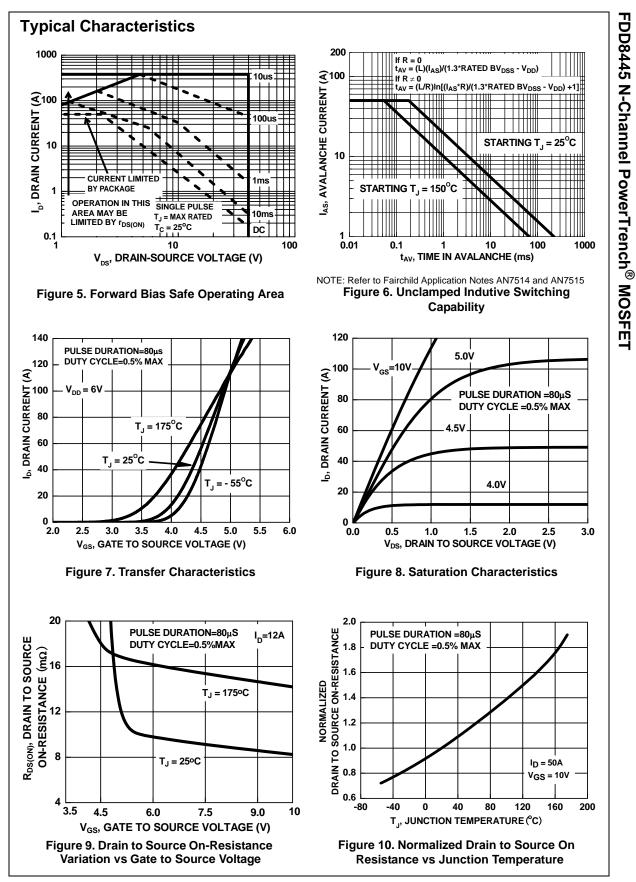
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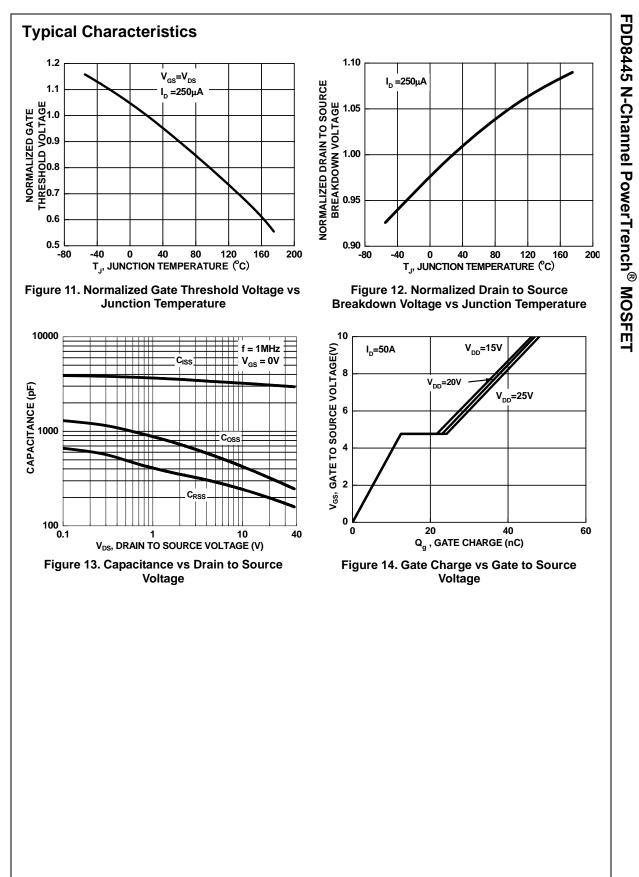
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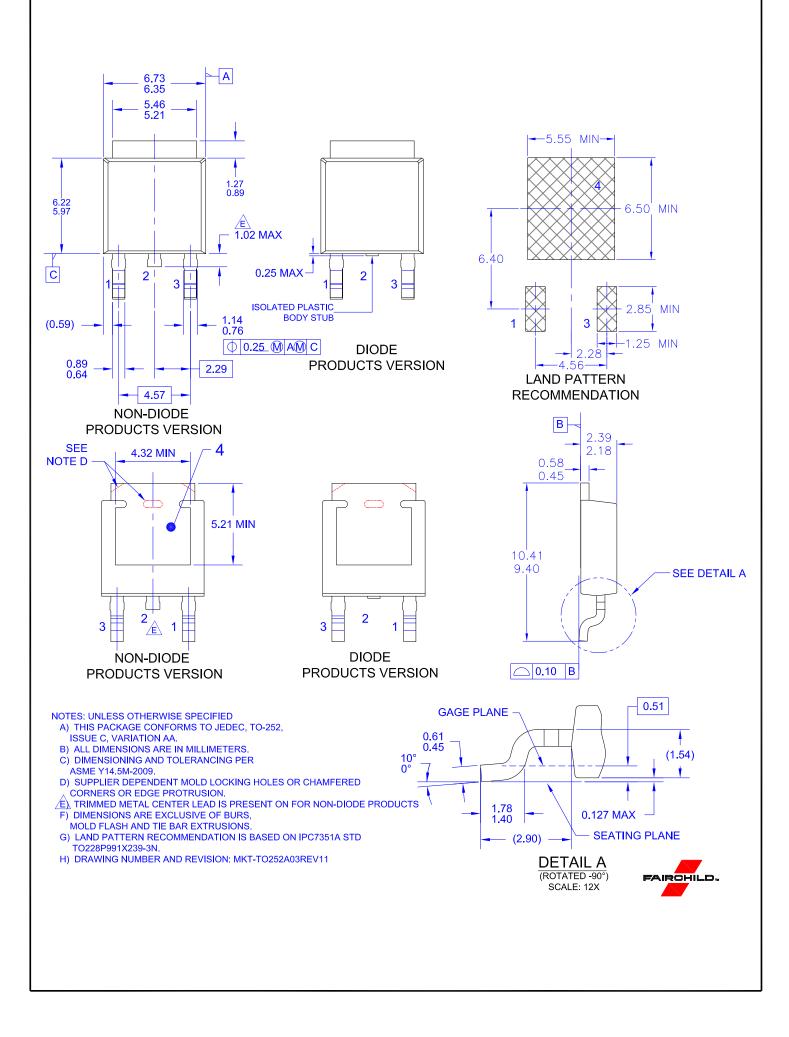




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